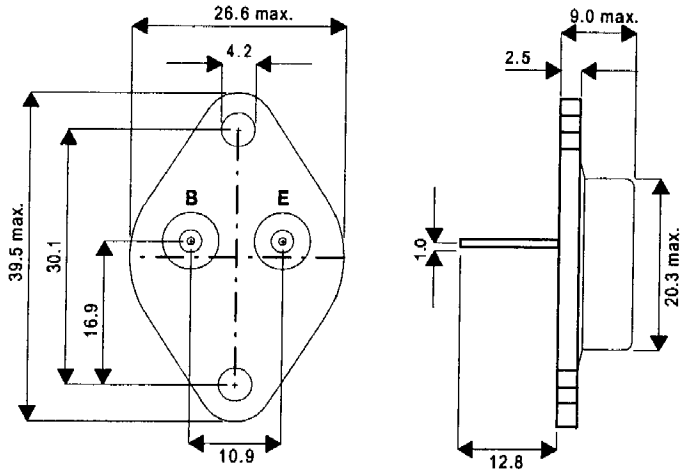


MECHANICAL DATA
 Dimensions in mm



TO3 Package.
 Case is collector.

**PNP
 DARLINGTON
 POWER
 TRANSISTOR
 BDX68
 BDX68A
 BDX68B
 BDX68C**

PNP Darlington transistors for audio output stages and general amplifier and switching applications.

NPN complements are:
 BDX69, BDX69A, BDX69B, BDX69C.

ABSOLUTE MAXIMUM RATINGS

		BDX 68	BDX 68A	BDX 68B	BDX 68C
		($T_{case} = 25^{\circ}C$ unless otherwise stated)			
V_{CBO}	Collector – Base Voltage (Open Emitter)	-60V	-80V	-100V	-120V
V_{CEO}	Collector – Emitter Voltage (Open Base)	-60V	-80V	-100V	-120V
V_{EBO}	Emitter – Base Voltage (Open Collector)	-5V	-5V	-5V	-5V
I_C	Collector Current	-25A			
I_{CM}	Collector Current (Peak)	-40A			
I_B	Base Current	-500mA			
P_{tot}	Total Power Dissipation at $T_{case} = 25^{\circ}C$	200W			
T_J	Maximum Junction Temperature	200°C			
T_{STG}	Storage Junction Temperature	-65 to 200°C			
$R_{\theta J-MB}$	Thermal Resistance, Junction to Mounting Base.	0.875°C / W			



BDX68
BDX68A
BDX68B
BDX68C

ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Units
I_{CBO} Collector Cut-off Current	$I_E = 0$ $V_{CB} = V_{CBOmax}$			2	mA
	$I_E = 0$ $V_{CB} = \frac{1}{2}V_{CBOmax}$ $T_J = 200^\circ\text{C}$			10	
I_{CEO} Collector Cut-off Current	$I_B = 0$ $V_{CE} = \frac{1}{2}V_{CEOmax}$			6	mA
I_{EBO} Emitter Cut-off Current	$I_C = 0$ $V_{EB} = -5\text{V}$			10	mA
h_{FE}^* D.C. Current Gain	$I_C = -5\text{A}$ $V_{CE} = -3\text{V}$		3000		—
	$I_C = -20\text{A}$ $V_{CE} = -3\text{V}$	1000			
	$I_C = -30\text{A}$ $V_{CE} = -3\text{V}$		1000		
V_{BE}^* Base – Emitter Voltage	$I_C = -20\text{A}$ $V_{CE} = -3\text{V}$			2.5	V
V_{CEsat}^* Collector - Emitter Saturation Voltage	$I_C = -20\text{A}$ $I_B = -80\text{mA}$			2	V
C_c Collector Capacitance	$I_E = I_B = 0$ $V_{CB} = -10\text{V}$ $f = 1\text{MHz}$		600		pF
f_{hfe} Cut-off Frequency	$I_C = -10\text{A}$ $V_{CE} = -3\text{V}$		60		kHz
$ h_{fe} $ Small Signal Current Gain	$I_C = -10\text{A}$ $V_{CE} = -3\text{V}$ $f = 1\text{MHz}$		20		—
V_F Diode, Forward Voltage	$I_F = 20\text{A}$		2		V
t_{on} Turn-on Time	$I_{Con} = -20\text{A}$		1		μs
t_{off} Turn-off Time	$I_{Bon} = -I_{Boff} = -80\text{mA}$		3.5		

* Pulse Test: $t_p < 300\mu\text{s}$, $\delta < 2\%$